Product data sheet

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NXP Semiconductors



General purpose PIN diode

BAP51-02

FEATURES

- Low diode capacitance
- Low diode forward resistance.

APPLICATIONS

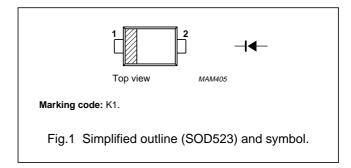
· General RF applications.

DESCRIPTION

General purpose PIN diode in a SOD523 ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		_	60	٧
I _F	continuous forward current		_	50	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	715	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	_	0.95	1.1	V
V _R	reverse voltage	I _R = 10 μA	50	_	_	V
I _R	reverse current	V _R = 50 V	_	_	100	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	_	0.4	_	pF
		V _R = 1 V; f = 1 MHz	_	0.3	0.55	pF
		V _R = 5 V; f = 1 MHz	_	0.2	0.35	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	_	5.5	9	Ω
		I _F = 1 mA; f = 100 MHz; note 1	_	3.6	6.5	Ω
		I _F = 10 mA; f = 100 MHz; note 1	_	1.5	2.5	Ω

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	85	K/W

General purpose PIN diode

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GRAPHICAL DATA

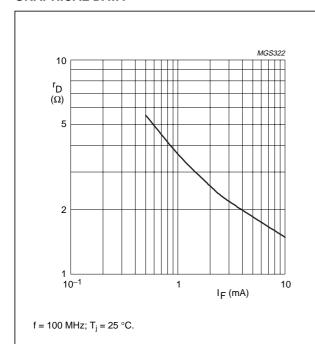


Fig.2 Forward resistance as a function of forward current; typical values.

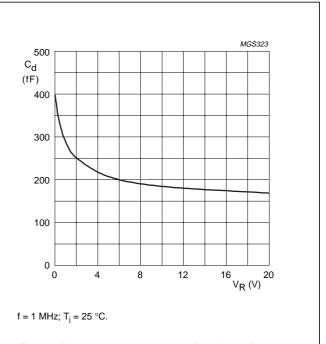


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

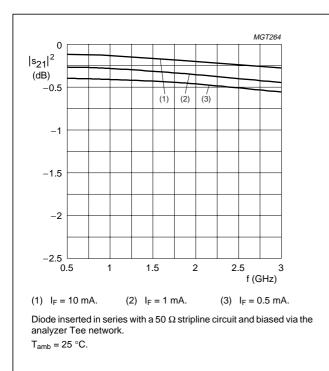
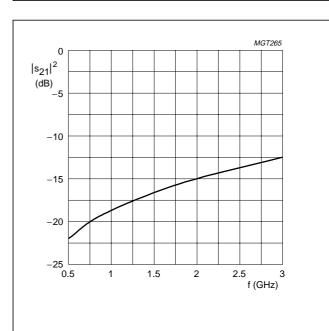


Fig.4 Insertion loss $(|s_{21}|^2)$ of the diode as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50 Ω stripline circuit. T_{amb} = 25 $^{\circ}C.$

Fig.5 Isolation ($|s_{21}|^2$) of the diode as a function of frequency; typical values.

NXP Semiconductors Product specification

General purpose PIN diode

BAP51-02

PROJECTION

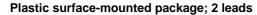
-02-12-13

06-03-16

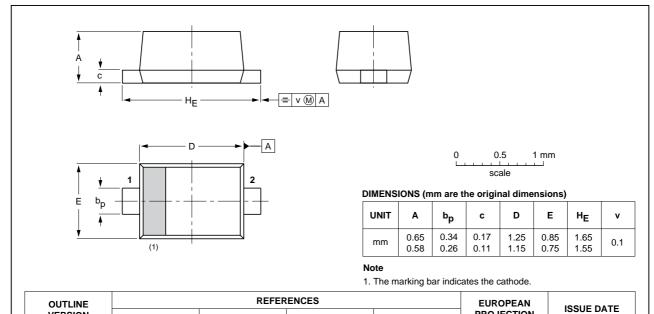
PACKAGE OUTLINE

VERSION

SOD523



SOD523



JEITA

SC-79

JEDEC

NXP Semiconductors BAP51-02

General purpose PIN diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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NXP Semiconductors BAP51-02

General purpose PIN diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP51-02_N_3	20080102	Product data sheet	-	BAP51-02_2
Modifications:	 Package ou 	tline drawing on page 4 chang	ed	
BAP51-02_2 (9397 750 07151)	20000706	Product specification	-	BAP51-02_N_1
BAP51-02_N_1 (9397 750 06152)	19990628	Preliminary specification	-	-

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